



50V N-Channel Enhancement Mode MOSFET - ESD Protected

Voltage

50 V

Current

350mA

Features

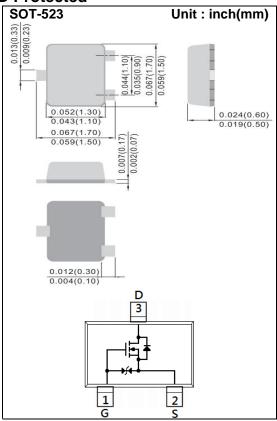
- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@500mA<1.6\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_{D}@200mA<2.5\Omega$
- R_{DS(ON)} , V_{GS}@2.5V, I_D@100mA<4.5Ω
- Advanced Trench Process Technology
- Specially Designed for Battery Operated Systems, Solid-State Relays Drivers: Relay, Displays, Memories, etc
- ESD Protected 2KV HBM
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC61249 standard

Mechanical Data

• Case: SOT-523 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.00007 ounces, 0.002 grams



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	50	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 20		
Continuous Drain Current (Note 4)		I _D	350	mA	
Pulsed Drain Current (Note 1)		I _{DM}	1200		
Power Dissipation	T _A =25°C	P _D	223	mW	
	Derate above 25°C		1.8	mW/°C	
Operating Junction and Storage Temperature Range		T_{J} , T_{STG}	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient (Note 3,4)		$R_{ heta JA}$	560	°C/W	





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	50	-	-	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	0.8	1	1.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =500mA	-	0.96	1.6	Ω
		V _{GS} =4.5V, I _D =200mA	-	1.25	2.5	
		V _{GS} =2.5V, I _D =100mA	-	2.73	4.5	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =50V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I_{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 10	
Dynamic (Note 5)						
Total Gate Charge	Q_g	V _{DS} =25V, I _D =250mA, V _{GS} =4.5V ^(Note 1,2)	-	0.63	1	nC
Gate-Source Charge	Q_gs		-	0.2	-	
Gate-Drain Charge	Q_gd		-	0.23	-	
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V, f=1MHZ	-	25	50	pF
Output Capacitance	Coss		-	9.5	20	
Reverse Transfer Capacitance	Crss		-	2.1	5	
Turn-On Delay Time	td _(on)	V_{DD} =25V, I_{D} =500mA, V_{GS} =10V, R_{G} =6 Ω (Note 1,2)	-	2.2	5	
Turn-On Rise Time	tr			19.2	38	ns
Turn-Off Delay Time	td _(off)			6.2	12	
Turn-Off Fall Time	tf		-	23	50	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	Is		-	-	500	mA
Diode Forward Voltage	V _{SD}	I _S =500mA, V _{GS} =0V	-	0.86	1.5	V

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. mounted on a 1 inch square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

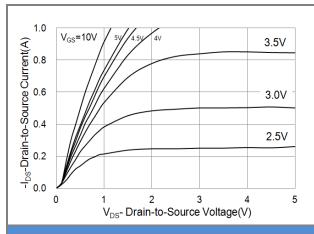


Fig.1 On-Region Characteristics

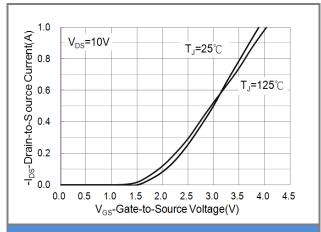


Fig.2 Transfer Characteristics

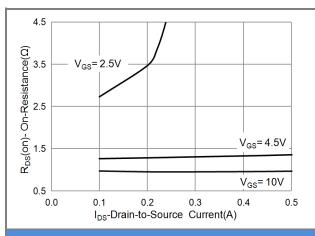


Fig.3 On-Resistance vs. Drain Current

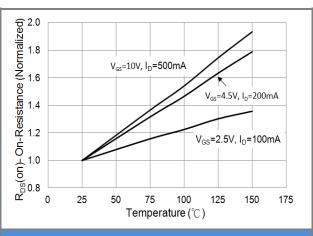
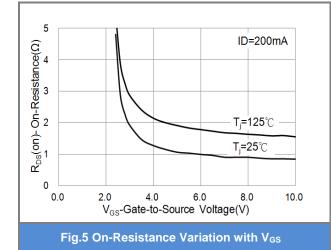


Fig.4 On-Resistance vs. Junction temperature



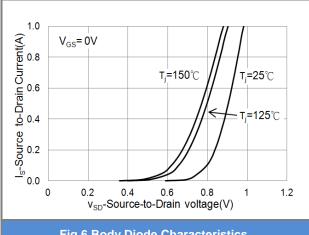


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

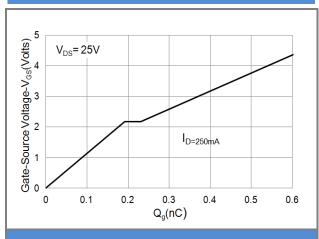


Fig.7 Gate-Charge Characteristics

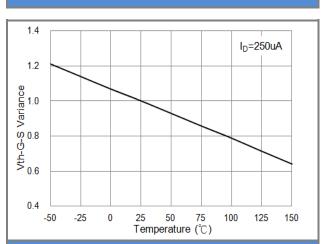


Fig.9 Threshold Voltage Variation with Temperature

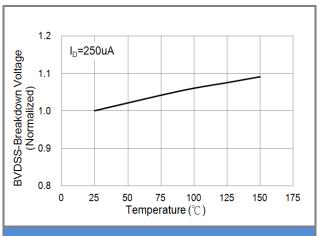


Fig.8 Breakdown Voltage Variation vs. Temperature

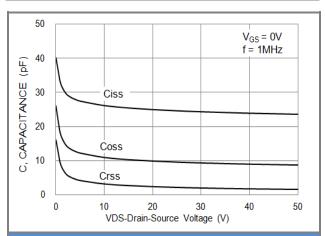


Fig.10 Capacitance vs. Drain-Source Voltage

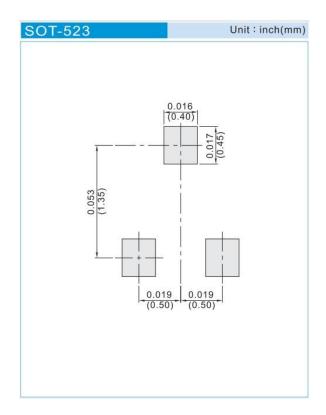




Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJE138K-AU_R1_000A1	SOT-523	4K pcs / 7" reel	8KT	Halogen free

Mounting Pad Layout







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